

# 210R GSD8R66T [610-635W]

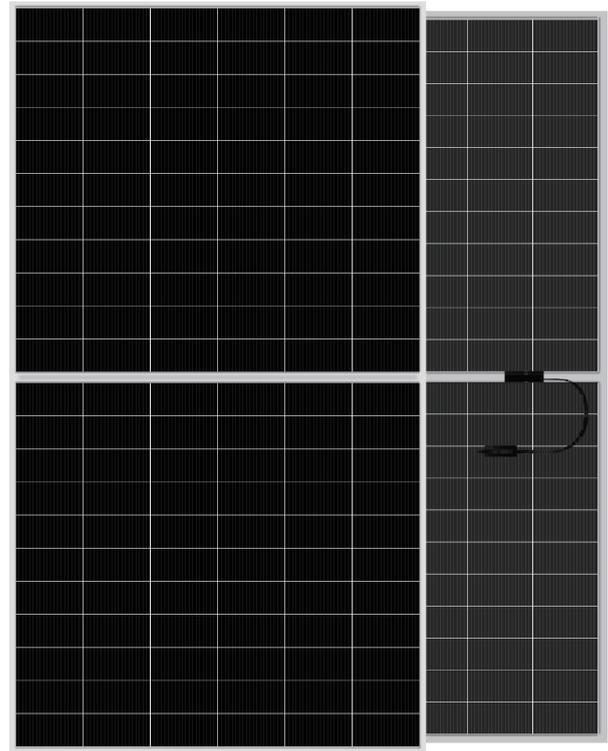
Bifacial Dual Glass Half-cut Mono TOPCon

IEC 61215 / IEC 61730 / UL 61730

ISO9001: 2015: Quality Management System

ISO14001:2015: Environment Management System

ISO45001:2018: Occupational Health And Safety Management System



## KEY FEATURES



### SMBB Technology

Better light trapping and current collection to improve module power output and reliability



### Lower Attenuation

Modules have better reliability and lower LID/LETID attenuation



### Double Power Output

For higher power output, backside power output can be increased 5-25%



### Wider Application

No water-permeability and high wear-resistance, can be widely used in high-humid, windy and dusty area



### PID Resistance

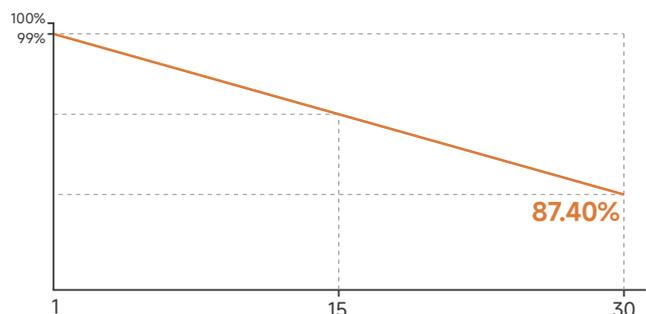
Excellent Anti-PID performance guarantee via optimized mass-production process and materials control

## Guaranteed Power Performance

**15** Years Product Warranty

**30** Years Linear Power Warranty

**0.40%** Annual Degradation Over 30 Years



As different markets have different certification requirements, please consult our G-Star sales group to obtain the corresponding certification for the local market. If any special requirements are needed for the specific installing environment, please feel free to contact G-star technical support department anytime.

# GSD8R66T 610-635W

Bifacial Dual Glass Half-cut Mono TOPCon

## Weight

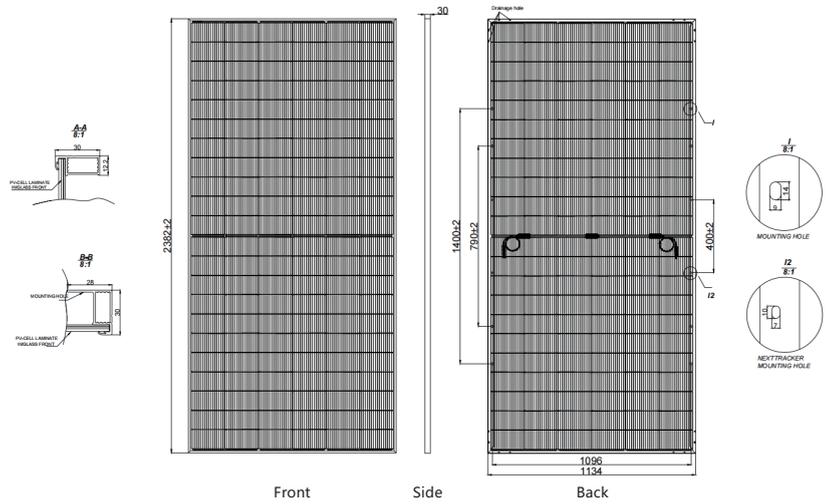
33 kg

## Dimensions

2382X1134X30mm

## Packaging

36pcs/pallet, 720pcs/ 40'HQ Container



## OPERATING CONDITIONS

Operating Temperature	-40°C~+85°C
Maximum System Voltage	1500V/DC
Maximum Series Fuse Rating	30A
Power Tolerance	0~+3%
Temperature Coefficients Of Pmax	-0.30%/°C
Temperature Coefficients Of Voc	-0.25%/°C
Temperature Coefficients Of Isc	0.046%/°C
Nominal Module Operating Temperature(NMOT)	43±2°C
*Under STC :BACKside Output Ration =Pmax(rear)/Pmax(front) 80%±5%	

## MECHANICAL CHARACTERISTICS

Cell Type	N type Monocrystalline 182.3*105mm
No. Of Cells	132 pcs in series (6x22)
Front Glass	2.0mm, Anti-Reflection Coating
Back Glass	2.0mm, Heat Strengthened Glass
Frame	Anodized Aluminium Alloy
Junction Box	IP68, 3Bypass Diodes
Output Cables	300mm in legh or Customized Length
Connectors	MC4/MC4-EVO2
Mechanical Load	5400Pa(Front)/2400Pa(Back)

## ELECTRICAL PARAMETERS AT STC

Module Type	GSD8R66T-610WT	GSD8R66T-615WT	GSD8R66T-620WT	GSD8R66T-625WT	GSD8R66T-630WT	GSD8R66T-635WT
Maximum Power(Pmax)	610	615	620	625	630	635
Maximum Power Voltage (Vmp)	40.73	40.95	41.17	41.40	41.62	41.84
Maximum Power Current (Imp)	14.98	15.02	15.06	15.10	15.14	15.18
Open-Circuit Voltage (Voc)	48.54	48.76	48.98	49.20	49.42	49.64
Short-Circuit Current (Isc)	15.75	15.79	15.83	15.87	15.91	15.95
Module Efficiency STC (%)	22.58%	22.77%	22.95%	23.14%	23.32%	23.51%

STC: Irradiance 1000W/m<sup>2</sup>, AM=1.5, Cell temperature 25°C.

## ELECTRICAL PARAMETERS AT BSTC\*\*

Maximum Power(Pmax)	675	680	686	691	697	702
Maximum Power Voltage (Vmp)	40.73	40.95	41.17	41.40	41.62	41.84
Maximum Power Current (Imp)	16.58	16.61	16.67	16.7	16.75	16.78
Open-Circuit Voltage (Voc)	48.54	48.76	48.98	49.20	49.42	49.64
Short-Circuit Current (Isc)	17.42	17.46	17.51	17.55	17.59	17.64
Module Efficiency STC (%)	24.99%	25.17%	25.40%	25.58%	25.80%	25.99%

\*\*BSTC: Front side irradiation 1000W/m<sup>2</sup>, Back side reflection irradiation 135W/m<sup>2</sup>, AM=1.5, Cell temperature 25°C.

## IV-CURVE

